

# $\mu$ PA2821T1L

# MOS FIELD EFFECT TRANSISTOR

R07DS0753EJ0100 Rev.1.00 May 25, 2012

### Description

The  $\mu$ PA2821T1L is N-channel MOS Field Effect Transistor designed for power management applications of a notebook computer and Lithium-Ion battery protection circuit.

### **Features**

- $V_{DSS} = 30 \text{ V } (T_A = 25^{\circ}\text{C})$
- Low on-state resistance
  - $R_{DS(on)} = 3.8 \text{ m}\Omega \text{ MAX}. (V_{GS} = 10 \text{ V}, I_D = 26 \text{ A})$
- 4.5 V Gate-drive available
- Small surface mount package (8-pin HVSON (3333))
- Pb-free, Halogen Free

### **Ordering Information**

Part No.	Lead Plating	Packing	Package
μPA2821T1L-E1-AT *1	Pure Sn (Tin)	Tape 3000 p/reel	8-pin HVSON (3333)
μPA2821T1L-E2-AT *1			typ. 0.028 g

Note: \*1. Pb-free (This product does not contain Pb in external electrode and other parts.)

## Absolute Maximum Ratings $(T_A = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	30	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	V <sub>GSS</sub>	±20	V
Drain Current (DC) (T <sub>C</sub> = 25°C)	I <sub>D(DC)</sub>	±26	Α
Drain Current (pulse) *1	I <sub>D(pulse)</sub>	±104	А
Total Power Dissipation *2	P <sub>T1</sub>	1.5	W
Total Power Dissipation (PW = 10 sec) *2	P <sub>T2</sub>	3.8	W
Total Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>T3</sub>	52	W
Channel Temperature	T <sub>ch</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C
Single Avalanche Current *3	I <sub>AS</sub>	18	Α
Signal Avalanche Energy *3	Eas	32.4	mJ

### **Thermal Resistance**

Channel to Ambient Thermal Resistance  $^{*2}$  R<sub>th(ch-A)</sub> 83.3 °C/W Channel to Case (Drain) Thermal Resistance R<sub>th(ch-C)</sub> 2.4 °C/W

Notes: \*1. PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

\*2. Mounted on a glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mmt

\*3. Starting  $T_{ch}$  = 25°C,  $V_{DD}$  = 15 V,  $R_G$  = 25  $\Omega$ ,  $V_{GS}$  = 20  $\rightarrow$  0 V, L = 100  $\mu H$ 

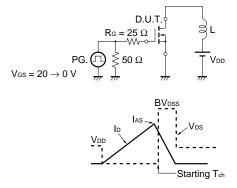
# Electrical Characteristics (T<sub>A</sub> = 25°C)

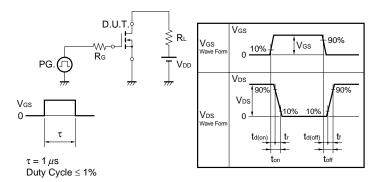
Item	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			1	μА	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$
Gate Leakage Current	I <sub>GSS</sub>			±10	μА	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$
Gate Cut-off Voltage	$V_{GS(off)}$	1.0		2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Forward Transfer Admittance *1	y <sub>fs</sub>	14			S	$V_{DS} = 5 \text{ V}, I_{D} = 6.5 \text{ A}$
Drain to Source On-state	R <sub>DS(on)1</sub>		3.0	3.8	mΩ	$V_{GS} = 10 \text{ V}, I_D = 26 \text{ A}$
Resistance *1	R <sub>DS(on)2</sub>		4.9	10.5	mΩ	$V_{GS} = 4.5 \text{ V}, I_D = 6.5 \text{ A}$
Input Capacitance	C <sub>iss</sub>		2490		pF	$V_{DS} = 10 \text{ V},$
Output Capacitance	Coss		820		pF	$V_{GS} = 0 V$ ,
Reverse Transfer Capacitance	C <sub>rss</sub>		740		pF	f = 1 MHz
Turn-on Delay Time	t <sub>d(on)</sub>		29		ns	$V_{DD} = 15 \text{ V}, I_D = 13 \text{ A},$
Rise Time	t <sub>r</sub>		69		ns	$V_{GS} = 10 \text{ V},$
Turn-off Delay Time	t <sub>d(off)</sub>		98		ns	$R_G = 10 \Omega$
Fall Time	t <sub>f</sub>		54		ns	
Total Gate Charge	$Q_G$		51		nC	V <sub>GS</sub> = 10 V,
			32		nC	$V_{GS} = 5 \text{ V}$
Gate to Source Charge	$Q_{GS}$		4		nC	$V_{DD} = 15 \text{ V},$
Gate to Drain Charge	$Q_{GD}$		22		nC	I <sub>D</sub> = 26 A
Body Diode Forward Voltage *1	$V_{F(S-D)}$		0.9		V	$I_F = 26 \text{ A}, V_{GS} = 0 \text{ V}$
Reverse Recovery Time	t <sub>rr</sub>		49		ns	$I_F = 26 \text{ A}, V_{GS} = 0 \text{ V},$
Reverse Recovery Charge	Qrr		41		nC	di/dt = 100 A/μs

Note: \*1. Pulsed

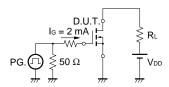
### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

## TEST CIRCUIT 2 SWITCHING TIME





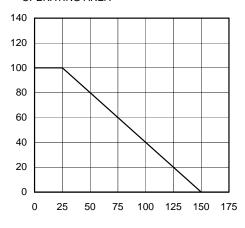
### **TEST CIRCUIT 3 GATE CHARGE**



dT - Percentage of Rated Power - %

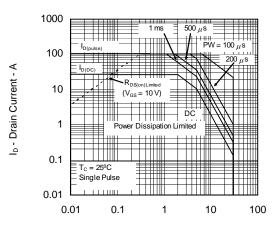
## Typical Characteristics (T<sub>A</sub> = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



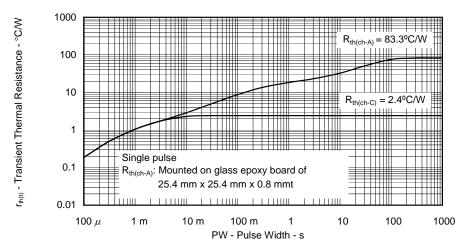
T<sub>C</sub> - Case Temperature - °C

### FORWARD BIAS SAFE OPERATING AREA

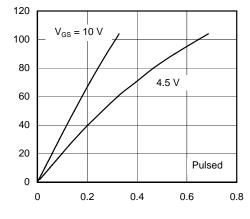


V<sub>DS</sub> - Drain to Source Voltage - V

### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

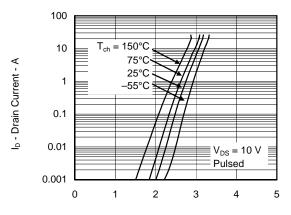


DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



 $V_{\text{\scriptsize DS}}$  - Drain to Source Voltage - V

### FORWARD TRANSFER CHARACTERISTICS

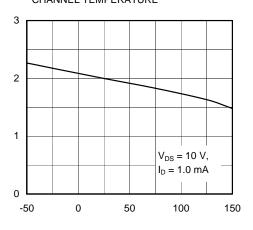


 $V_{\text{GS}}$  - Gate to Source Voltage - V

I<sub>D</sub> - Drain Current - A



# GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

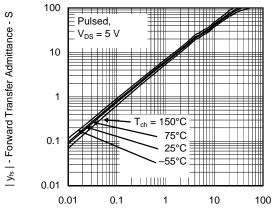


T<sub>ch</sub> - Channel Temperature - °C

# F -

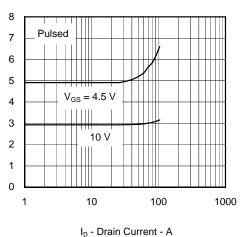
R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

# FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

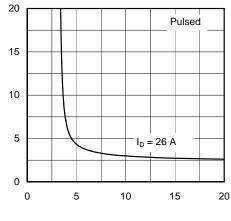


ID - Drain Current - A

# DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

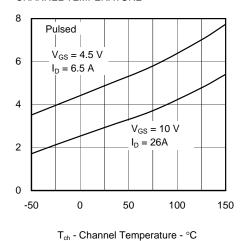


# DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

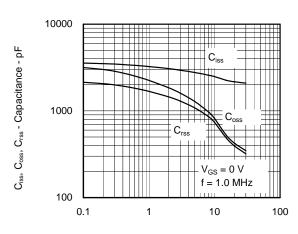


V<sub>GS</sub> - Gate to Source Voltage - V

# DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

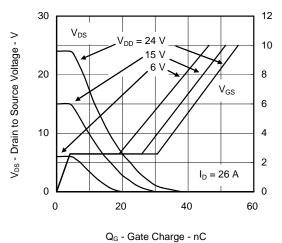


 $V_{DS}$  - Drain to Source Voltage - V

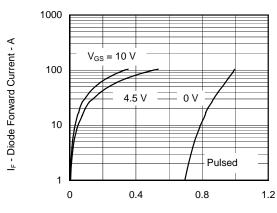
 $\mathsf{R}_{\mathsf{DS}(\varpi)}$  - Drain to Source On-state Resistance -  $m\Omega$ 

### DYNAMIC INPUT/OUTPUT CHARACTERISTICS

## TERISTICS SOURCE TO DRAIN DIODE FORWARD VOLTAGE



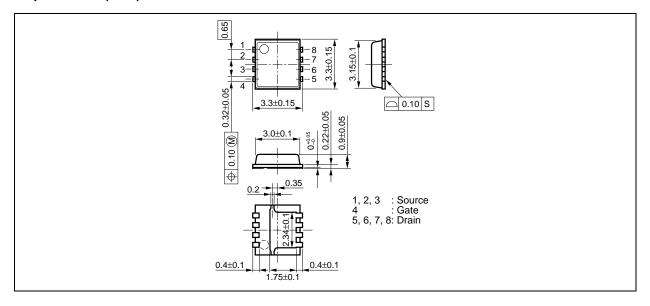




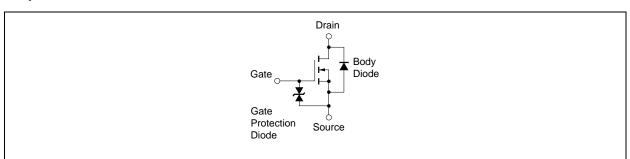
 $V_{\text{F(S-D)}}$  - Source to Drain Voltage - V

## Package Drawings (Unit: mm)

## 8-pin HVSON (3333)



## **Equivalent Circuit**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Po	vicion	History
Re	vision	пізіої у

# $\mu$ PA2821T1L Data Sheet

Ī			Description		
	Rev.	Date	Page	Summary	
Ī	1.00	May 25, 2012	_	First Edition Issued	

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